Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.013 inches	
Overall Height:	
Between 0.005 inches and 0.008 inches	
Overall Width:	
0.013 inches	
Function For Which Designed:	
Switching	
Mounting Method:	
Press fit	
Features Provided:	
Mounting pad	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
100.0 breakdown voltage, dc	
Current Rating Per Characteristic:	
10.00 microamperes forward current, average peak	
Power Rating Per Characteristic:	
200.0 milliwatts small-signal input power, common-collector	
Capacitance Rating In Picofarads:	
0.1	
Maximum Operating Tempurature Per Measurement Point:	
85.0 degrees celsius ambient air	
Special Features:	
The diode shall be capable of fulfilling all requirements when attached to gold plated aluminum using a silver filled conductive	epoxy;
junction pattern arrangement: pn	
Precious Material And Location:	
Terminal surfaces gold	
Precious Material:	
Gold	
Terminal Type And Quantity:	
1 bonding pad	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Filg:	
A110a0	